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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	180MHz
Connectivity	CSIO, EBI/EMI, I²C, LINbus, SD, SmartCard, SPI, UART/USART, USB
Peripherals	DMA, I²S, LVD, POR, PWM, WDT
Number of I/O	121
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 24x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/s6e2gk6h0agv2000a

S6E2G Series

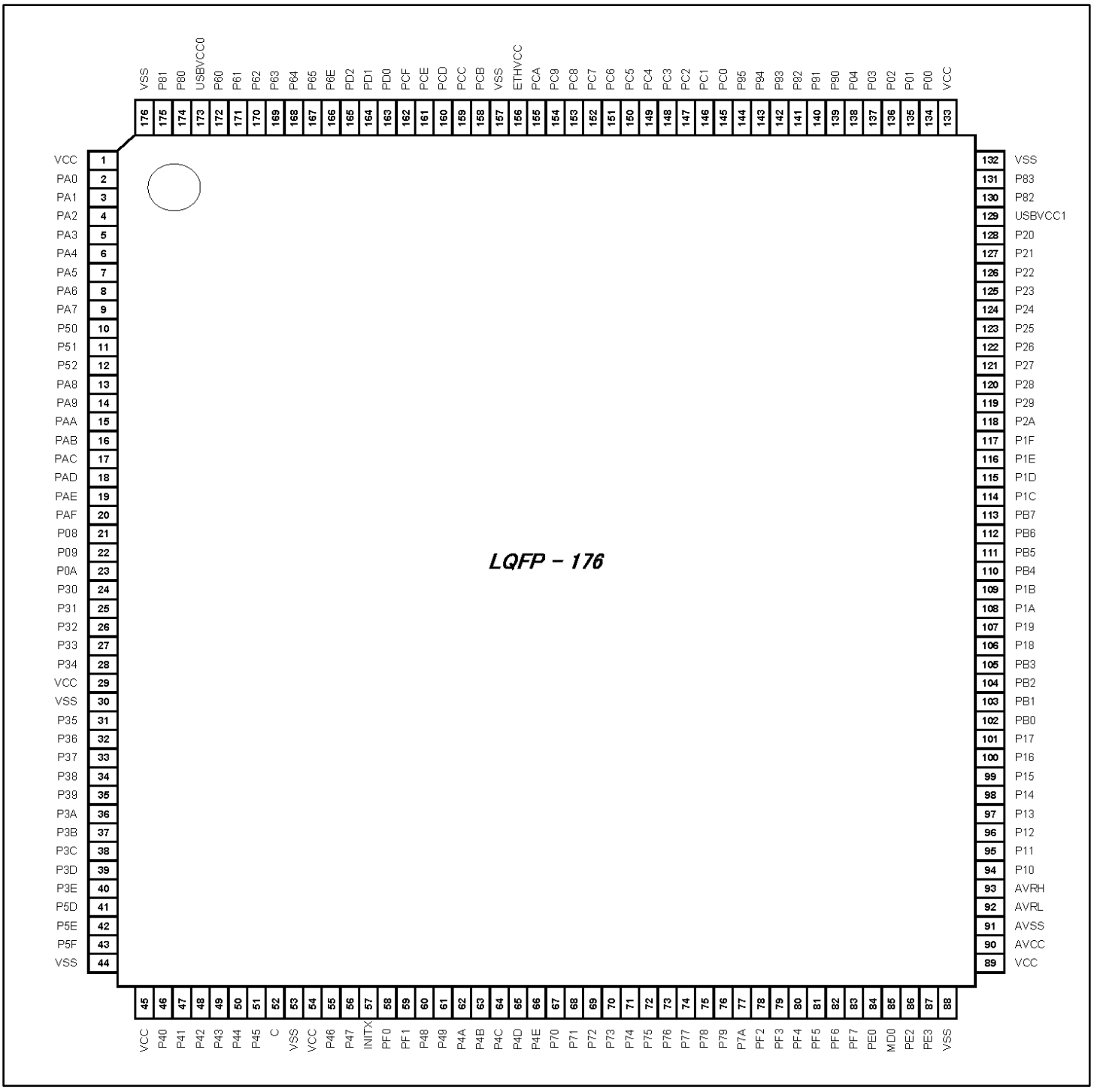
32-bit ARM® Cortex®-M4F FM4 Microcontroller

S6E2G Series are FM4 devices with up to 180 MHz CPU, 1 MB flash, 192 KB SRAM, 20x communication peripherals, 33x digital peripherals and 3x analog peripherals. They are designed for industrial automation and metering applications.

Devices in the S6E2G Series are highly integrated 32-bit microcontrollers with high performance and competitive cost. This series is based on the ARM Cortex-M4F processor with on-chip flash memory and SRAM. The series has peripherals such as motor control timers, A/D converters, and communications interfaces (USB, CAN, UART, CSIO (SPI), I^2C, LIN). The products that are described in this data sheet are placed into TYPE5-M4 product categories in the "FM4 Family Peripheral Manual Main Part (002-04856)".

- 32-bit ARM Cortex-M4F Core
  - Up to 180 MHz frequency operation
- On-chip Memories
  - Flash memory: Up to 1024 Kbytes
  - SRAM memory:
    - SRAM0: up to 128 Kbytes
    - SRAM1: 32 Kbytes
    - SRAM2: 32 Kbytes
- Direct Memory Access (DMA) Controller (Eight Channels)
- Descriptor System Data Transfer Controller (DSTC); 256 channels
- External Bus Interface
- USB Interface (Max two channels): Host and Device
- CAN Interface (Max one channel) Available on S6E2GM and S6E2GH Devices Only
- Multi-function Serial Interface (Max 10 Channels)
  - UART (Universal Asynchronous Receiver/Transmitter)
  - Clock Synchronous Serial Interface (CSIO (SPI))
  - Local Interconnect Network (LIN)
  - Inter-Integrated Circuit (I^2C)
  - Inter-IC Sound (I^2S)
- Base Timer (Max 16 channels)
- General Purpose I/O Port
  - Up to 121 high-speed general-purpose I/O ports in 144-pin package
  - Up to 153 high-speed general-purpose I/O ports in 176-pin package
- Multi-function Timer (Max two units)
- Real-Time Clock (RTC)
- Analog to Digital Converter (ADC) (Max 32 Channels)
- Dual Timer (32-/16-bit Down Counter)
- Quadrature Position/Revolution Counter (QPRC; Max two channels)
- Watch Counter
- External Interrupt Controller Unit
- Watchdog Timer (Two channels)
- Cyclic Redundancy Check (CRC) Accelerator
- SD Card Interface Available on S6E2GM, S6E2GH, and S6E2GK Devices Only
- Ethernet-MAC Available on S6E2GM, S6E2GK, and S6E2G2 Devices only
- Smartcard Interface (Max 2 channels)
- Five Clock Sources
- Six Reset Sources
- Clock Supervisor (CSV)
- Low-Voltage Detector (LVD)
- Six Low-power Consumption Modes
  - Sleep
  - Timer
  - RTC
  - Stop
  - Deep standby RTC
  - Deep standby stop
- Peripheral Clock Gating System
- Crypto Assist Function
- Debug
  - Serial wire JTAG debug port (SWJ-DP)
  - Embedded trace macrocells (ETM) provide comprehensive debug and trace facilities.
  - AHB trace macrocells (HTM)
- 41-bit Unique ID
- Wide range voltage: VCC = 2.7 to 5.5 V

LQP176



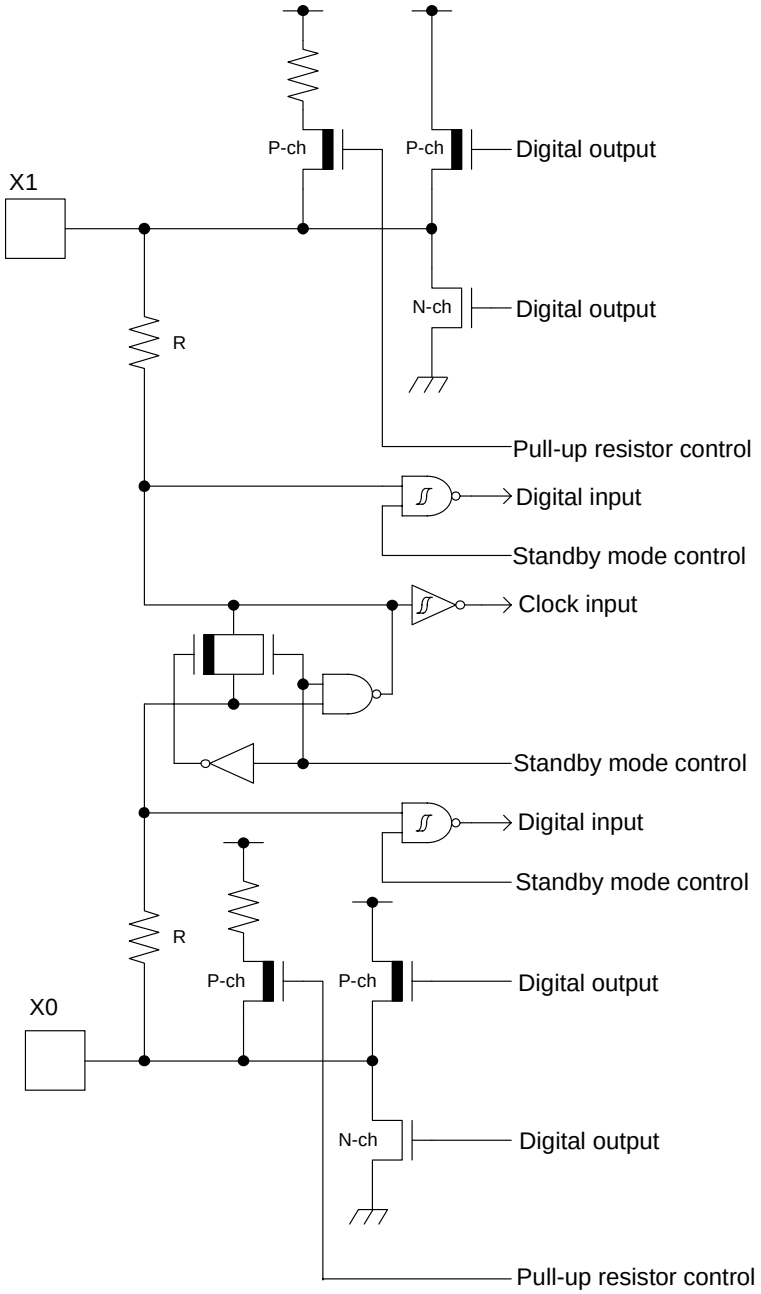
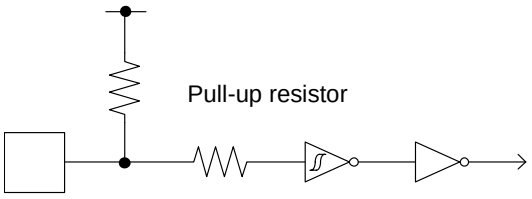
Note:

- *Only the GPIO function is shown on GPIO pins. See the table in Pin Descriptions for the full, multiplexed signal name.*

Module	Pin Name	Function	Pin Number	
			LQFP 176	LQFP 144
GPIO	P30	General-purpose I/O port 3	24	-
	P31		25	-
	P32		26	21
	P33		27	22
	P34		28	23
	P35		31	26
	P36		32	27
	P37		33	28
	P38		34	29
	P39		35	30
	P3A		36	31
	P3B		37	32
	P3C		38	33
	P3D		39	34
	P3E		40	35
	P40	General-purpose I/O port 4	46	38
	P41		47	39
	P42		48	40
	P43		49	41
	P44		50	42
	P45		51	43
	P46		55	47
	P47		56	48
	P48		60	50
	P49		61	51
	P4A		62	52
	P4B		63	53
	P4C		64	54
	P4D		65	55
	P4E		66	56
	P50	General-purpose I/O port 5	10	-
	P51		11	-
	P52		12	-
	P5D		41	-
	P5E		42	-
	P5F		43	-
	P60	General-purpose I/O port 6	172	140
	P61		171	139
	P62		170	138
	P63		169	137
	P64		168	-
	P65		167	-
	P6E		166	136

Module	Pin Name	Function	Pin Number	
			LQFP 176	LQFP 144
SD I/F	S_CLK_0	SD memory card interface SD memory card clock output pin	28	23
	S_CMD_0	SD memory card interface SD memory card command output	31	26
	S_DATA1_0	SD memory card interface SD memory card data bus	26	21
	S_DATA0_0		27	22
	S_DATA3_0		32	27
	S_DATA2_0		33	28
	S_CD_0	SD memory card interface SD memory card detection pin	35	30
	S_WP_0	SD memory card interface SD memory card write protection	34	29
Ethernet	E_COL	Collision detection	154	124
	E_COUT	Clock output for Ethernet PHY	158	128
	E_CRS	Carrier detection	155	125
	E_MDC	Management clock	152	122
	E_MDIO	Management data I/O	151	121
	E_PPS	PTP counter monitor	166	136
	E_RX00	Received data0	149	119
	E_RX01	Received data1	148	118
	E_RX02	Received data2	147	117
	E_RX03	Received data3	146	116
	E_RXCK_REFCK	Received clock input/ Reference clock	153	123
	E_RXDV	Received data enable	150	120
	E_RXER	Received data error detection	145	115
	E_TCK	Transition clock input	159	129
	E_TX00	Transition data0	164	134
	E_TX01	Transition data1	163	133
	E_TX02	Transition data2	162	132
	E_TX03	Transition data3	161	131
	E_TXEN	Transition data enable	165	135
	E_TXER	Transition data error detection	160	130

7. I/O Circuit Type

Type	Circuit	Remarks
A		It is possible to select the main Oscillation/GPIO function. When the main oscillation is selected: ・ Oscillation feedback resistor: approximately 1 MΩ ・ Standby mode control When the GPIO is selected: ・ CMOS level output. ・ CMOS level hysteresis input ・ Pull-up resistor control ・ Standby mode control ・ Pull-up resistor: approximately 50 kΩ ・ I_{OH} = -4 mA, I_{OL} = 4 mA
B		・ CMOS level hysteresis input ・ Pull-up resistor: approximately 50 kΩ

Notes on Power-On

Turn power on/off in the sequence shown below or at the same time. If not using the A/D converter and D/A converter, connect AVCC = VCC and AVSS = VSS.

Turning on: VCC → USBVCC0
VCC → USBVCC1
VCC →ETHVCC
VCC → AVCC → AVRH
Turning off: AVRH → AVCC → VCC
ETHVCC → VCC
USBVCC1 → VCC
USBVCC0 → VCC

Serial Communication

There is a possibility of receiving incorrect data as a result of noise or other issues introduced by the serial communication. Take care to design the printed circuit board to minimize noise.

Consider the case of introducing error as a result of noise, perform error detection such as by applying a checksum of data at the end. If an error is detected, retransmit the data.

Differences in Characteristics within the Product Line

The electric characteristics including power consumption, ESD, latch-up, noise, and oscillation differ among members of the product line because chip layout and memory structures are not the same; for example, different sizes, flash versus ROM, etc. If you are switching to a different product of the same series, please make sure to evaluate the electric characteristics.

Pull-Up Function of 5 V Tolerant I/O

Please do not input the signal more than VCC voltage at the time of Pull-Up function use of 5 V tolerant I/O.

Pin Doubled as Debug Function

The pin doubled as TDO/TMS/TDI/TCK/TRSTX, SWO/SWDIO/SWCLK should be used as output only. Do not use as input.

Ethernet-MAC Pins

Pin Name	Ethernet-MAC Function	Except For Ethernet-MAC Function	Power Supply Type
P6E/ADTG_5/SCK4_1/INT29_0/E_PPS	E_PPS *	P6E/ADTG_5/SCK4_1/INT29_0	V_{CC}
PC0/E_RXER	E_RXER	PC0	$ETHV_{CC}$
PC1/TIOB6_0/E_RX03	E_RX03	PC1/TIOB6_0	
PC2/TIOA6_0/E_RX02	E_RX02	PC2/TIOA6_0	
PC3/TIOB7_0/E_RX01	E_RX01	PC3/TIOB7_0	
PC4/TIOA7_0/E_RX00	E_RX00	PC4/TIOA7_0	
PC5/TIOB14_0/E_RXDV	E_RXDV	PC5/TIOB14_0	
PC6/TIOA14_0/E_MDIO	E_MDIO	PC6/TIOA14_0	
PC7/INT13_0/E_MDC/CROUT_1	E_MDC	PC7/INT13_0/CROUT_1	
PC8/E_RXCK_REFCK	E_RXCK_REFCK	PC8	
PC9/TIOB15_0/E_COL	E_COL	PC9/TIOB15_0	
PCA/TIOA15_0/E_CRS	E_CRS	PCA/TIOA15_0	
PCB/INT28_0/E_COUT	E_COUT	PCB/INT28_0	
PCC/E_TCK	E_TCK	PCC	
PCD/SOT4_1/INT14_0/E_TXER	E_TXER	PCD/SOT4_1/INT14_0	
PCE/SIN4_1/INT15_0/E_TX03	E_TX03	PCE/SIN4_1/INT15_0	
PCF/RTS4_1/INT12_0/E_TX02	E_TX02	PCF/RTS4_1/INT12_0	
PD0/INT30_1/E_TX01	E_TX01	PD0/INT30_1	
PD1/INT31_1/E_TX00	E_TX00	PD1/INT31_1	
PD2/CTS4_1/E_TXEN	E_TXEN	PD2/CTS4_1	

*: It is used to confirm the PTP counter cycle in Ethernet-MAC by waveforms.

Table 12-6 Typical and Maximum Current Consumption in Sleep Operation (PLL), when PCLK0 = PCLK1 = PCLK2 = HCLK

Parameter	Symbol	Pin Name	Conditions	Frequency*4	Value		Unit	Remarks
					Typ*1	Max*2		
Power supply current	I_{CCS}	VCC	Sleep operation*5 (PLL)	72 MHz	32	90	mA	*3 When all peripheral clocks are on
				60 MHz	27	85	mA	
				48 MHz	23	81	mA	
				36 MHz	18	76	mA	
				24 MHz	13	71	mA	
				12 MHz	8.5	66	mA	
				8 MHz	6.9	64	mA	
				4 MHz	5.3	63	mA	
				72 MHz	15	73	mA	*3 When all peripheral clocks are off
				60 MHz	13	71	mA	
				48 MHz	11	69	mA	
				36 MHz	9.3	67	mA	
				24 MHz	7.3	65	mA	
				12 MHz	5.4	63	mA	
				8 MHz	4.7	62	mA	
				4 MHz	4.1	62	mA	

1: T_A = +25 °C, V_{CC} = 3.3 V

2: T_J = +125 °C, V_{CC} = 5.5 V

3: When all ports are input and are fixed at 0

4: Frequency is a value of HCLK when PCLK0 = PCLK1 = PCLK2 = HCLK

5: When using the crystal oscillator of 4 MHz (including the current consumption of the oscillation circuit)

Table 12-7 Typical and Maximum Current Consumption in Sleep Operation (Other than PLL), when PCLK0 = PCLK1 = PCLK2 = HCLK/2

Parameter	Symbol	Pin Name	Conditions	Frequency*4	Value		Unit	Remarks
					Typ*1	Max*2		
Power supply current	I_{CCS}	VCC	Sleep operation*5 (main oscillation)	4 MHz	2.6	60	mA	*3 When all peripheral clocks are on
					2.0	60	mA	*3 When all peripheral clocks are off
			Sleep operation (built-in High-speed CR)	4 MHz	2.0	60	mA	*3 When all peripheral clocks are on
					1.3	59	mA	*3 When all peripheral clocks are off
			Sleep operation*6 (sub oscillation)	32 kHz	0.46	58	mA	*3 When all peripheral clocks are on
					0.45	58	mA	*3 When all peripheral clocks are off
			Sleep operation (built-in low-speed CR)	100 kHz	0.47	58	mA	*3 When all peripheral clocks are on
					0.46	58	mA	*3 When all peripheral clocks are off

1: T_A = +25 °C, V_{CC} = 3.3 V

2: T_J = +125 °C, V_{CC} = 5.5 V

3: When all ports are input and are fixed at 0.

4: Frequency is a value of HCLK when PCLK0 = PCLK1 = PCLK2 = HCLK/2

5: When using the crystal oscillator of 4 MHz (including the current consumption of the oscillation circuit)

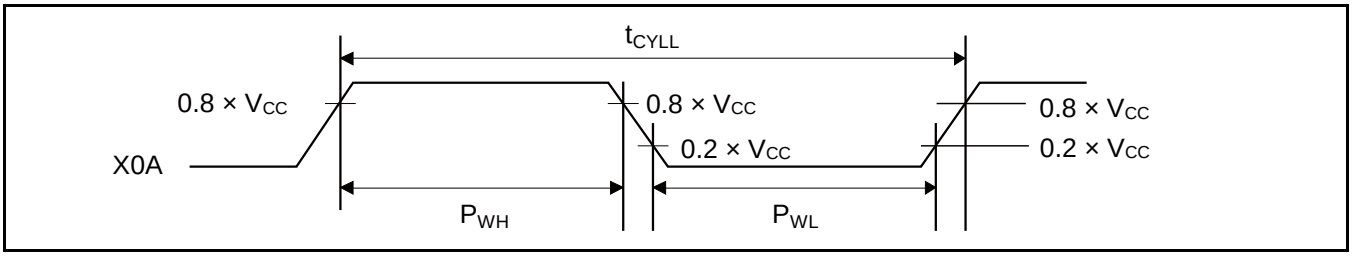
6: When using the crystal oscillator of 32 kHz (including the current consumption of the oscillation circuit)

12.4.2 Sub Clock Input Characteristics

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Input frequency	$1/t_{CYLL}$	X0A, X1A	-	-	32.768	-	kHz	When crystal oscillator is connected *
			-	32	-	100	kHz	When using external clock
Input clock cycle	t_{CYLL}		-	10	-	31.25	µs	When using external clock
Input clock pulse width	-		P_{WH}/t_{CYLL}, P_{WL}/t_{CYLL}	45	-	55	%	When using external clock

*: For more information about crystal oscillator, see Sub crystal oscillator in 9. Handling Devices.



12.4.3 Built-In CR Oscillation Characteristics

Built-In High-speed CR

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Conditions	Value			Unit	Remarks
			Min	Typ	Max		
Clock frequency	f_{CRH}	T_J = - 20°C to + 105°C	3.92	4	4.08	MHz	When trimmed *1
		T_J = - 40°C to + 125°C	3.88	4	4.12		
		T_J = - 40°C to + 125°C	2.9	4	5		When not trimmed
Frequency stabilization time	t_{CRWT}	-	-	-	30	µs	*2

1: In the case of using the values in CR trimming area of flash memory at shipment for frequency/temperature trimming

2: This is the time to stabilize the frequency of the High-speed CR clock after setting trimming value. During this period, it is able to use the High-speed CR clock as a source clock.

Built-In Low-speed CR

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Condition	Value			Unit	Remarks
			Min	Typ	Max		
Clock frequency	f_{CRL}	-	50	100	150	kHz	

NAND Flash Mode

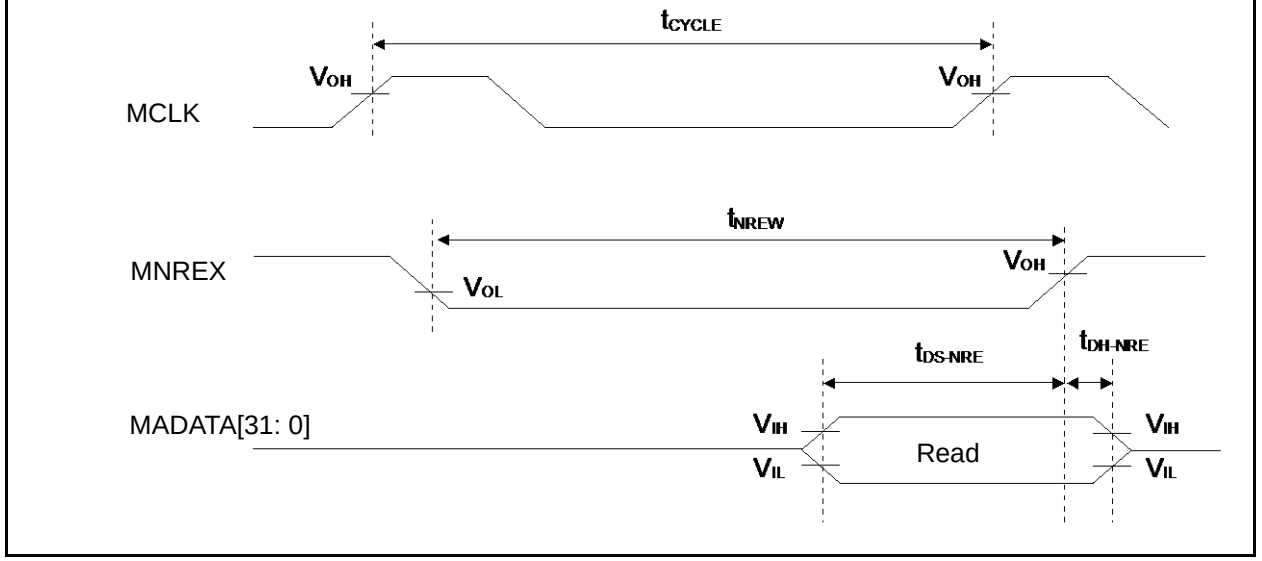
(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
MNREX Min pulse width	t_{NREW}	MNREX	-	MCLK×n-3	-	ns	
Data set up →MNREX ↑ time	t_{DS-NRE}	MNREX, MADATA[31: 0]	-	20	-	ns	
MNREX ↑ → Data hold time	t_{DH-NRE}	MNREX, MADATA[31: 0]	-	0	-	ns	
MNALE ↑ → MNWEX delay time	$t_{ALEH-NWEL}$	MNALE, MNWEX	-	MCLK×m-9	MCLK×m+9	ns	
MNALE ↓ → MNWEX delay time	$t_{ALEL-NWEL}$	MNALE, MNWEX	-	MCLK×m-9	MCLK×m+9	ns	
MNCLE ↑ → MNWEX delay time	$t_{CLEH-NWEL}$	MNCLE, MNWEX	-	MCLK×m-9	MCLK×m+9	ns	
MNWEX ↑ → MNCLE delay time	$t_{NWEH-CLEL}$	MNCLE, MNWEX	-	0	MCLK×m+9	ns	
MNWEX Min pulse width	t_{NWEW}	MNWEX	-	MCLK×n-3	-	ns	
MNWEX ↓ → Data output time	$t_{NWEL-DV}$	MNWEX, MADATA[31: 0]	-	-9	9	ns	
MNWEX ↑ → Data hold time	$t_{NWEH-DX}$	MNWEX, MADATA[31: 0]	-	0	MCLK×m+9	ns	

Note:

- *When the external load capacitance C_L = 30 pF (m = 0 to 15, n = 1 to 16)*

NAND Flash Read



SDRAM Mode

(V_{CC} = 2.7V to 3.6V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Value	Unit		Unit	Remarks
				Min	Max		
Output frequency	t_{CYCSD}	MSDCLK	-	-	50	MHz	
Address delay time	t_{AOSD}	MSDCLK, MAD[15: 0]	-	2	12	ns	
MSDCLK ↑ → Data output delay time	t_{DOSD}	MSDCLK, MADATA[31: 0]	-	2	12	ns	
MSDCLK ↑ → Data output Hi-Z time	t_{DOZSD}	MSDCLK, MADATA[31: 0]	-	2	19.5	ns	
MDQM[3: 0] delay time	t_{WROSD}	MSDCLK, MDQM[1: 0]	-	1	12	ns	
MCSX delay time	t_{MCSSD}	MSDCLK, MCSX8	-	2	12	ns	
MRASX delay time	t_{RASSD}	MSDCLK, MRASX	-	2	12	ns	
MCASX delay time	t_{CASSD}	MSDCLK, MCASX	-	2	12	ns	
MSDWEX delay time	t_{MWESD}	MSDCLK, MSDWEX	-	2	12	ns	
MSDCKE delay time	t_{CKESD}	MSDCLK, MSDCKE	-	2	12	ns	
Data set up time	t_{DSSD}	MSDCLK, MADATA[31: 0]	-	19	-	ns	
Data hold time	t_{DHSD}	MSDCLK, MADATA[31: 0]	-	0	-	ns	

Note:

- *When the external load capacitance C_L = 30 pF*

12.4.12 CSIO (SPI) Timing

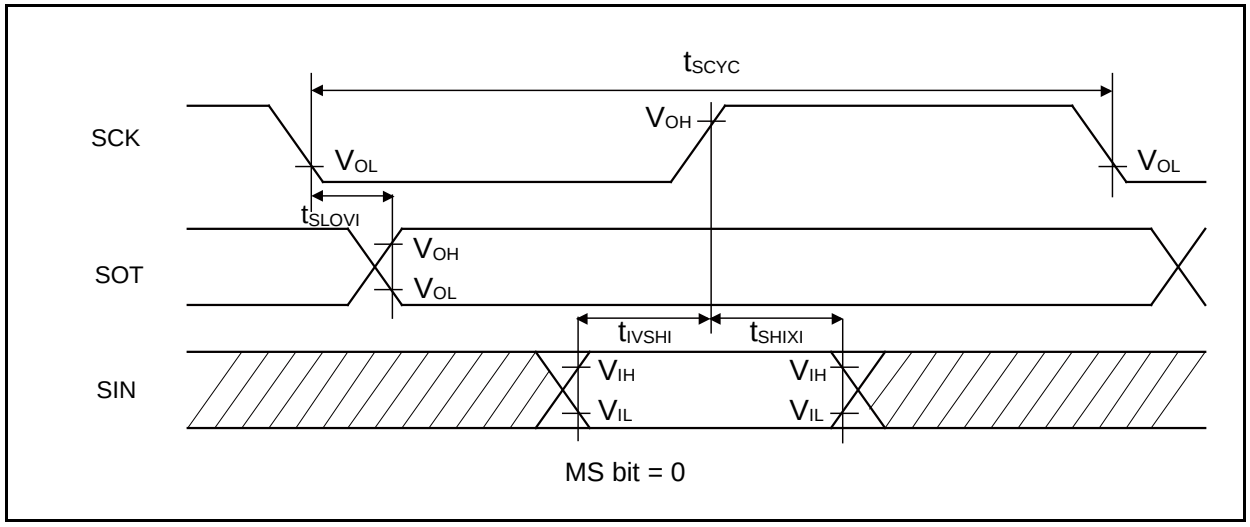
Synchronous Serial (SPI = 0, SCINV = 0)

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

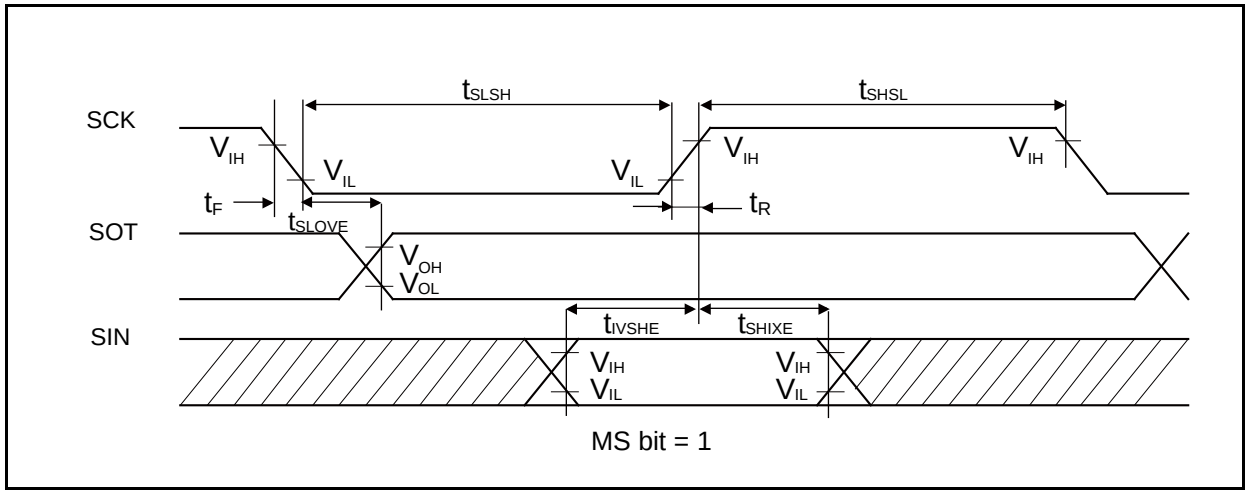
Parameter	Symbol	Pin Name	Conditions	V_{CC} < 4.5 V		V_{CC} ≥ 4.5 V		Unit
				Min	Max	Min	Max	
Baud rate	-	-	-	-	8	-	8	Mbps
Serial clock cycle time	t_{SCYC}	SCKx	Internal shift clock operation	$4t_{CYCP}$	-	$4t_{CYCP}$	-	ns
SCK↓→SOT delay time	t_{SLOVI}	SCKx, SOTx		- 30	+ 30	- 20	+ 20	ns
SIN→SCK↑ setup time	t_{IVSHI}	SCKx, SINx		50	-	30	-	ns
SCK↑→SIN hold time	t_{SHIXI}	SCKx, SINx		0	-	0	-	ns
Serial clock L pulse width	t_{SLSH}	SCKx	External shift clock operation	$2t_{CYCP}$ - 10	-	$2t_{CYCP}$ - 10	-	ns
Serial clock H pulse width	t_{SHSL}	SCKx		t_{CYCP} + 10	-	t_{CYCP} + 10	-	ns
SCK↓→SOT delay time	t_{SLOVE}	SCKx, SOTx		-	50	-	30	ns
SIN→SCK↑ setup time	t_{IVSHE}	SCKx, SINx		10	-	10	-	ns
SCK↑→SIN hold time	t_{SHIXE}	SCKx, SINx		20	-	20	-	ns
SCK fall time	t_F	SCKx		-	5	-	5	ns
SCK rise time	t_R	SCKx		-	5	-	5	ns

Notes:

- *The above characteristics apply to CLK synchronous mode.*
- *t_{CYCP} indicates the APB bus clock cycle time. For more information about the APB bus number to which the multi-function serial is connected, see 1. S6E2G Series Block Diagram in this data sheet.*
- *These characteristics only guarantee the same relocate port number; for example, the combination of SCLKx_0 and SOTx_1 is not guaranteed.*
- *When the external load capacitance C_L = 30 pF.*



MS bit = 0



MS bit = 1

High-Speed Synchronous Serial (SPI = 1, SCINV = 1)

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

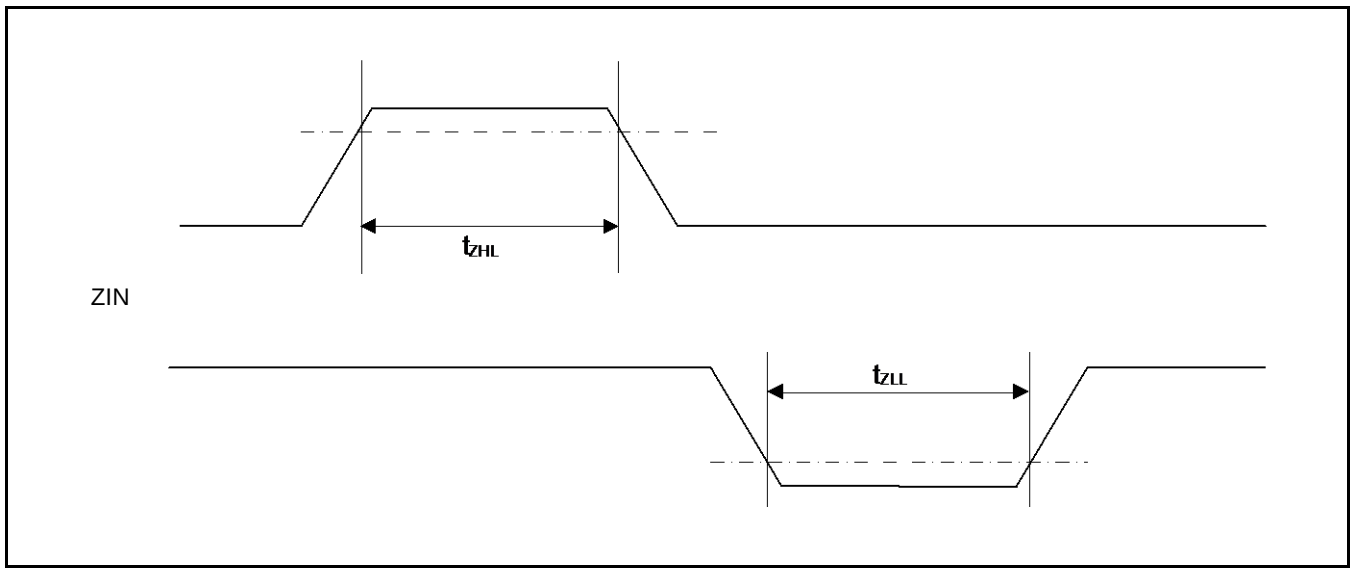
Parameter	Symbol	Pin Name	Conditions	V_{CC} < 4.5 V		V_{CC} ≥ 4.5 V		Unit
				Min	Max	Min	Max	
Serial clock cycle time	t_{SCYC}	SCKx	Internal shift clock operation	$4t_{CYCP}$	-	$4t_{CYCP}$	-	ns
SCK↓→SOT delay time	t_{SLOVI}	SCKx, SOTx		- 10	+ 10	- 10	+ 10	ns
SIN→SCK↑ setup time	t_{IVSHI}	SCKx, SINx		14 12.5*	-	12.5	-	ns
SCK↑→SIN hold time	t_{SHIXI}	SCKx, SINx		5	-	5	-	ns
SOT→SCK↑ delay time	t_{SOVHI}	SCKx, SOTx		$2t_{CYCP}$ - 10	-	$2t_{CYCP}$ - 10	-	ns
Serial clock L pulse width	t_{SLSH}	SCKx	External shift clock operation	$2t_{CYCP}$ - 5	-	$2t_{CYCP}$ - 5	-	ns
Serial clock H pulse width	t_{SHSL}	SCKx		t_{CYCP} + 10	-	t_{CYCP} + 10	-	ns
SCK↓→SOT delay time	t_{SLOVE}	SCKx, SOTx		-	15	-	15	ns
SIN→SCK↑ setup time	t_{IVSHE}	SCKx, SINx		5	-	5	-	ns
SCK↑→SIN hold time	t_{SHIXE}	SCKx, SINx		5	-	5	-	ns
SCK fall time	t_F	SCKx		-	5	-	5	ns
SCK rise time	t_R	SCKx		-	5	-	5	ns

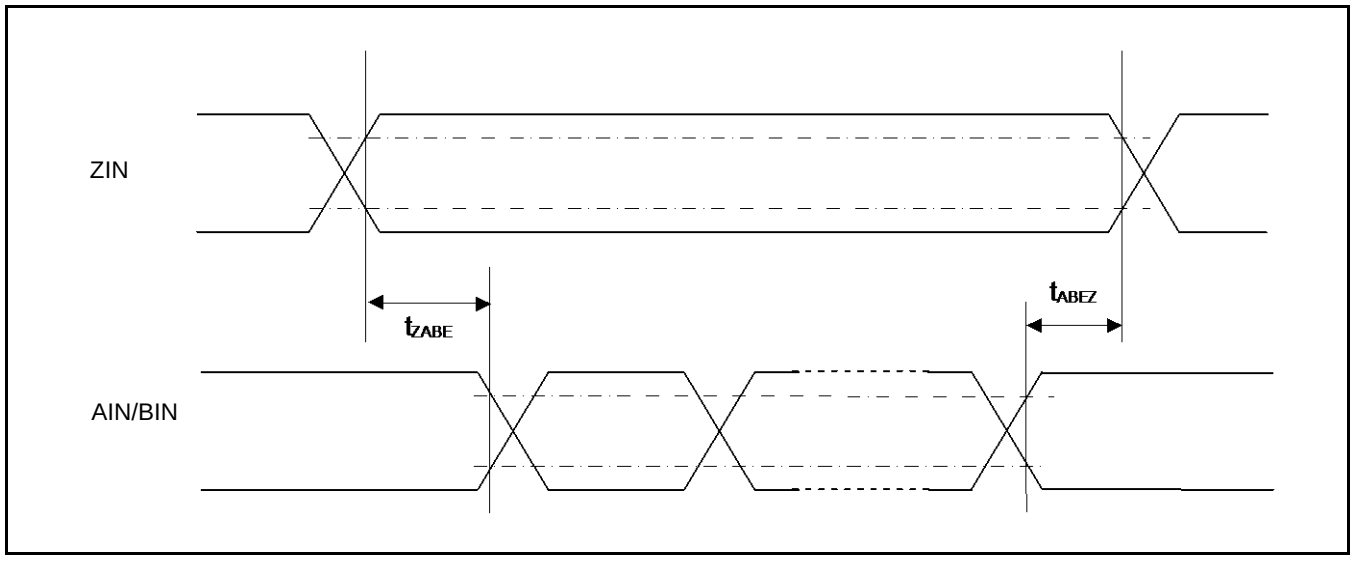
Notes:

- *The above characteristics apply to CLK synchronous mode.*
- *t_{CYCP} indicates the APB bus clock cycle time. For more information about the APB bus number to which the multi-function serial is connected, see 1. S6E2G Series Block Diagram in this data sheet.*
- *These characteristics only guarantee the following pins:*

  No chip select: SIN4_0, SOT4_0, SCK4_0

  Chip select: SIN6_0, SOT6_0, SCK6_0, SCS60_0, SCS61_0, SCS62_0, SCS63_0
- *When the external load capacitance C_L = 30 pF. (for *, when C_L = 10 pF)*


ZIN
tZHL
tZLL


ZIN
tZABE
tABEZ
AIN/BIN

12.4.19 Ethernet-MAC Timing

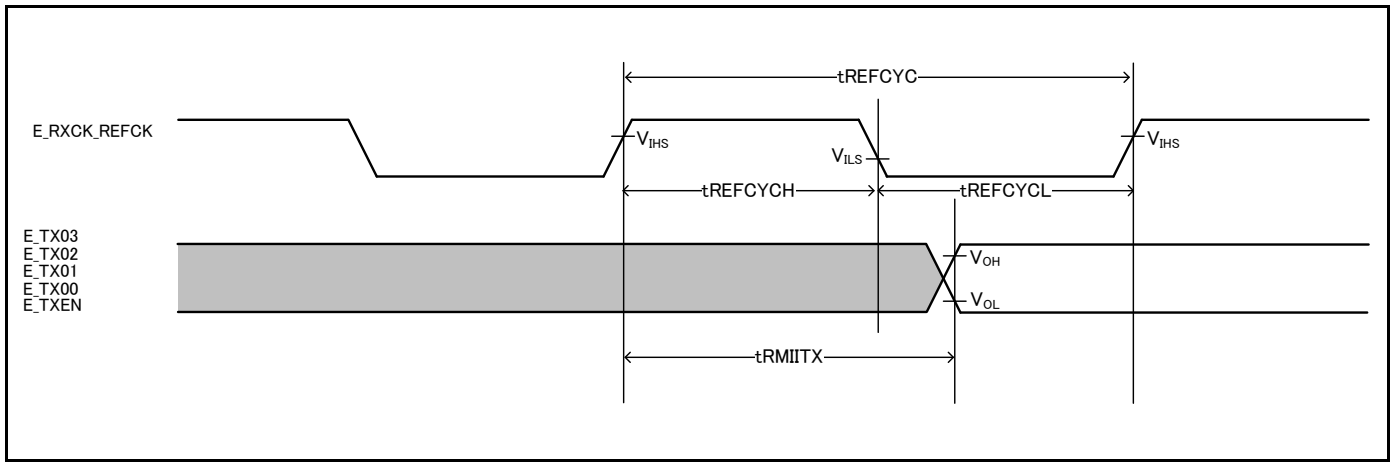
RMII Transmission (100 Mbps/10 Mbps)

($ETHV_{CC}$ = 3.0V to 3.6V, 4.5V to 5.5V*1, V_{SS} = 0V, C_L = 25 pF)

Parameter	Symbol	Pin Name	Conditions	Value		Unit
				Min	Max	
Reference clock cycle time*2	t_{REFCYC}	E_RXCK_REFCK	20 ns (typical)	-	-	ns
Reference clock High-pulse-width duty cycle	$t_{REFCYCH}$	E_RXCK_REFCK	$t_{REFCYCH}/t_{REFCYC}$	35	65	%
Reference clock Low-pulse-width duty cycle	$t_{REFCYCL}$	E_RXCK_REFCK	$t_{REFCYCL}/t_{REFCYC}$	35	65	%
REFCK ↑ → Transmitted data delay time	t_{RMIITX}	E_TX03, E_RX02, E_TX01, E_TX00, E_TXEN	-	-	12	ns

*1: When ETHV = 4.5 V to 5.5 V, it is recommended to add a series resistor at the output pin to suppress the output current.

*2: The reference clock is fixed to 50 MHz in the RMII specifications. The clock accuracy should meet the PHY-device specifications.



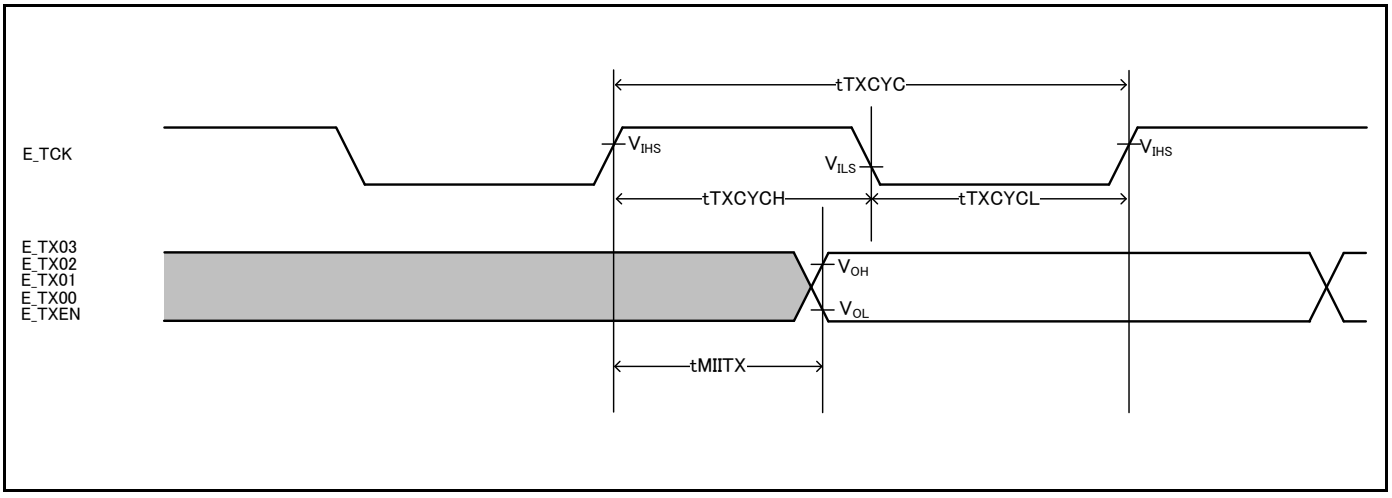
MII Transmission (100 Mbps/10 Mbps)

($ETHV_{CC}$ = 3.0V to 3.6V, 4.5V to 5.5V[*1], V_{SS} = 0V, C_L = 25 pF)

Parameter	Symbol	Pin Name	Conditions	Value		Unit
				Min	Max	
Transmission clock Cycle time*2	t_{TXCYC}	E_TCK	100 Mbps 40 ns (typical)	-	-	ns
			100 Mbps 400 ns (typical)	-	-	ns
Transmission clock High-pulse-width duty cycle	t_{TXCYCH}	E_TCK	t_{TXCYCH}/t_{TXCYC}	35	65	%
Transmission clock Low-pulse-width duty cycle	t_{TXCYCL}	E_TCK	t_{TXCYCL}/t_{TXCYC}	35	65	%
TXCK ↑ → Transmitted data delay time	t_{MIITX}	E_TX03, E_TX02, E_TX01, E_TX00, E_TXEN	-	-	24	ns

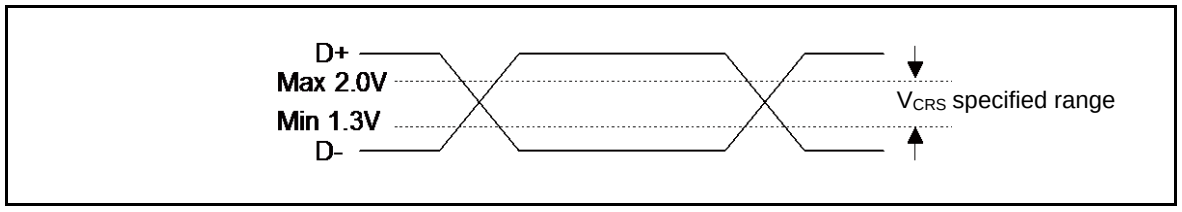
1: When ETHV = 4.5 V to 5.5 V, it is recommended to add a series resistor at the output pin to suppress the output current.

2: The transmission clock is fixed to 25 MHz or 2.5 MHz in the MII specifications. The clock accuracy should meet the PHY-device specifications.

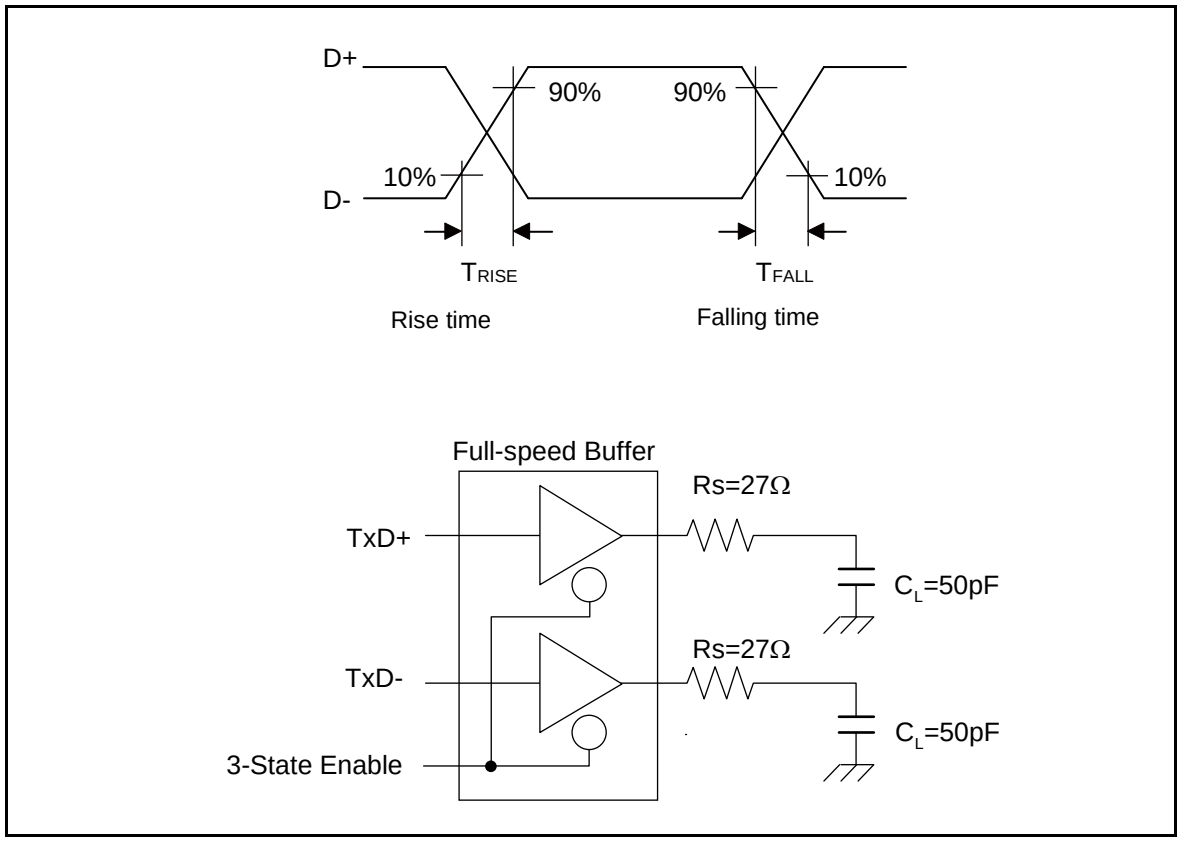


3: The output drive capability of the driver is below 0.3 V at low state (V_{OL}) (to 3.6 V and 1.5 kΩ load), and 2.8 V or above (to the VSS and 1.5 kΩ load) at high state (V_{OH}).

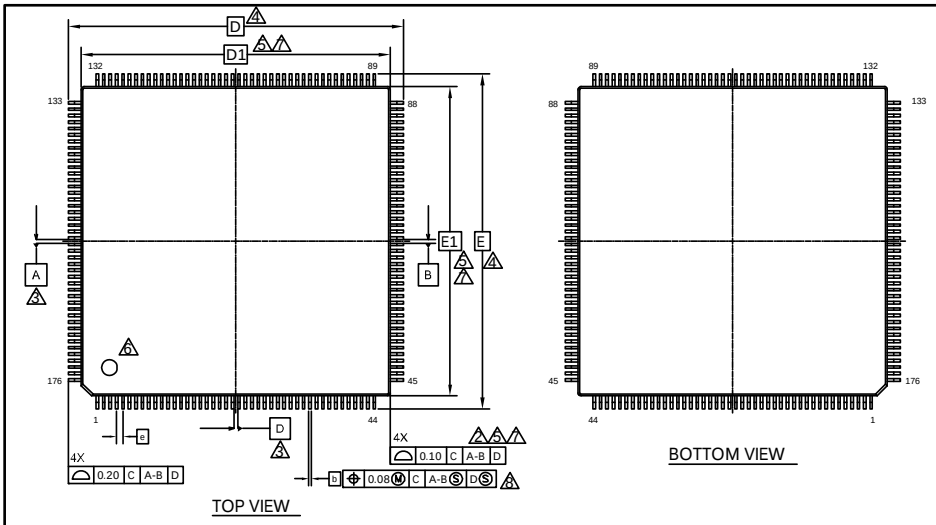
4: The cross voltage of the external differential output signal (D +/D −) of USB I/O buffer is within 1.3 V to 2.0 V.



5: They indicate rise time (t_{RISE}) and fall time (t_{FALL}) of the full-speed differential data signal.
They are defined by the time between 10% and 90% of the output signal voltage.
For full-speed buffer, t_R/t_F ratio is regulated as within ± 10% to minimize RFI emission.



Package Type	Package Code
LQFP 176	LQP176



SYMBOL	DIMENSIONS		
	MIN.	NOM.	MAX.
A	—	—	1.70
A1	0.05	—	0.15
b	0.17	0.22	0.27
c	0.09	—	0.20
D		26.00 BSC	
D1		24.00 BSC	
e		0.50 BSC	
E		26.00 BSC	
E1		24.00 BSC	
L	0.45	0.60	0.75
L1	0.30	0.50	0.70
θ	0°	—	8°

NOTES

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DATUM PLANE H IS LOCATED AT THE BOTTOM OF THE MOLD PARTING LINE COINCIDENT WITH WHERE THE LEAD EXITS THE BODY.
3. DATUMS A-B AND D TO BE DETERMINED AT DATUM PLANE H.
4. TO BE DETERMINED AT SEATING PLANE C.
5. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25mm PRE SIDE. DIMENSIONS D1 AND E1 INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
6. DETAILS OF PIN 1 IDENTIFIER ARE OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED.
7. REGARDLESS OF THE RELATIVE SIZE OF THE UPPER AND LOWER BODY SECTIONS. DIMENSIONS D1 AND E1 ARE DETERMINED AT THE LARGEST FEATURE OF THE BODY EXCLUSIVE OF MOLD FLASH AND GATE BURRS. BUT INCLUDING ANY MISMATCH BETWEEN THE UPPER AND LOWER SECTIONS OF THE MOLDER BODY.
8. DIMENSION b DOES NOT INCLUDE DAMBER PROTRUSION. THE DAMBAR PROTRUSION (S) SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED b MAXIMUM BY MORE THAN 0.08mm. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE LEAD FOOT.
9. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10mm AND 0.25mm FROM THE LEAD TIP.
10. A1 IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.

PACKAGE OUTLINE, 176 LEAD LQFP
24.0X24.0X1.7 MM LQP176 REV**

002-15150 **